



DMT616MLSS

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|-------------------------------|--|
| 60V | 14mΩ @ V _{GS} = 10V | 10A |
| | 21mΩ @ V _{GS} = 4.5V | 8.1A |

Description and Applications

This MOSFET is designed to minimize the on-state resistance $(R_{DS(ON)})$ and maintain superior switching performance, which makes it ideal for high-efficiency power management applications.

- High-Frequency Switching
- Synchronous Rectification
- DC-DC Converters

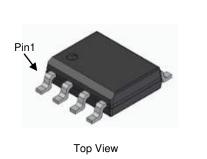
60V N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

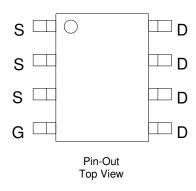
- 100% Unclamped Inductive Switching (UIS) Test in Production— Ensures More Reliable and Robust End Application
- High Conversion Efficiency
- Low R_{DS(ON)}—Minimizes On-State Losses
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

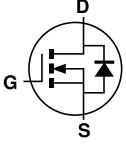
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish—Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 3
- Weight: 0.076 grams (Approximate)



SO-8





Equivalent Circuit

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|---------------|------|------------------|
| DMT616MLSS-13 | SO-8 | 2500/Tape & Reel |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

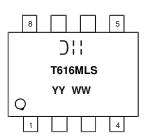
2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:



):: = Manufacturer's Marking T616MLS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 19 = 2019) WW = Week (01 to 53)



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | |
|--|---|------------------|---------|----|
| Drain-Source Voltage | | V _{DSS} | 60 | V |
| Gate-Source Voltage | | V _{GSS} | ±20 | V |
| Continuous Drain Current (Note 6) V_{GS} = 10V | $T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$ | I _D | 10 8 | A |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%) | • | I _{DM} | 70 | A |
| Maximum Continuous Body Diode Forward Current | | Is | 10 | A |
| Pulsed Body Diode Forward Current (10µs Pulse, Duty Cy | cle = 1%) | I _{SM} | 70 | A |
| Avalanche Current, L = 0.1mH | | I _{AS} | 15.7 | A |
| Avalanche Energy, L = 0.1mH | | E _{AS} | 12.3 | mJ |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 1.39 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{OJA} | 90.1 | °C/W |
| Total Power Dissipation (Note 6) | PD | 2.06 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{OJA} | 60.7 | °C/W |
| Thermal Resistance, Junction to Case (Note 6) | R _{eJC} | 8.7 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|--------------------------|-----|------|------|------|--|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 60 | _ | — | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current | I _{DSS} | — | _ | 1 | μΑ | $V_{DS} = 48V, V_{GS} = 0V$ | |
| Gate-Source Leakage | I _{GSS} | — | — | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 7) | | | | | - | | |
| Gate Threshold Voltage | V _{GS(TH)} | 1.2 | — | 2.2 | V | $V_{DS}=V_{GS},\ I_{D}=250\mu A$ | |
| Static Drain-Source On-Resistance | Basian | _ | 10.9 | 14 | mΩ | $V_{GS} = 10V, I_D = 8.5A$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 15.8 | 21 | | $V_{GS}=4.5V,\ I_D=6A$ | |
| Diode Forward Voltage | V _{SD} | _ | 0.7 | 1.2 | V | $V_{GS} = 0V, I_S = 1A$ | |
| DYNAMIC CHARACTERISTICS (Note 8) | | | | | | | |
| Input Capacitance | Ciss | _ | 785 | — | | $\label{eq:VDS} \begin{array}{l} V_{DS}=30V, \ V_{GS}=0V, \\ f=1MHz \end{array}$ | |
| Output Capacitance | Coss | _ | 281 | — | pF | | |
| Reverse Transfer Capacitance | Crss | — | 27 | — | | | |
| Gate Resistance | R _g | — | 1.5 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ | |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | — | 7.3 | - | | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | _ | 13.6 | — | nC | $V_{DS}=30V,\ I_{D}=10A$ | |
| Gate-Source Charge | Q _{gs} | _ | 2.2 | — | no | | |
| Gate-Drain Charge | Q _{gd} | _ | 3.4 | _ | | | |
| Turn-On Delay Time | t _{D(ON)} | | 3.2 | _ | | $\label{eq:VGS} \begin{split} V_{GS} &= 10V, V_{DS} = 30V, \\ R_G &= 6\Omega, I_D = 10A \end{split}$ | |
| Turn-On Rise Time | t _R | | 4.4 | _ | | | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 14.7 | — | ns | | |
| Turn-Off Fall Time | t _F | _ | 8.5 | _ | 1 | | |
| Reverse Recovery Time | t _{RR} | _ | 23.0 | _ | ns | | |
| Reverse Recovery Charge | Q _{RR} | _ | 14.1 | — | nC | I _F = 10A, di/dt = 100A/μs | |

Notes:

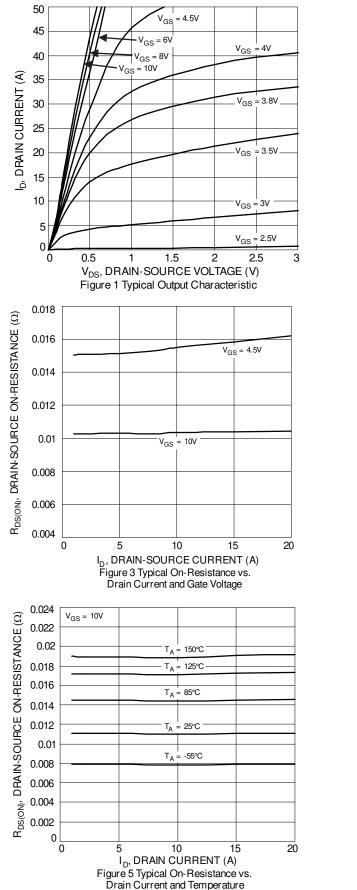
Device mounted on FR-4 PCB, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PCB, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.

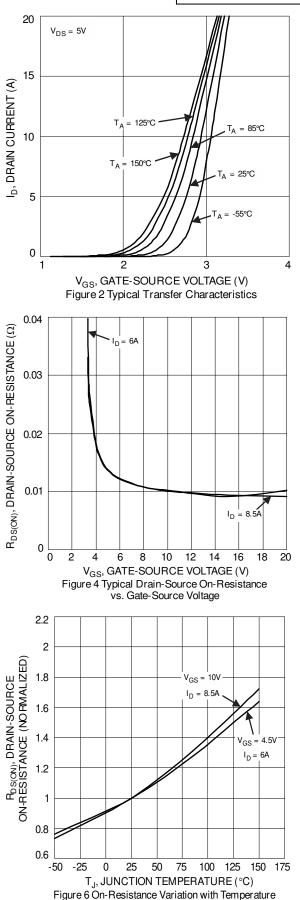
7. Short duration pulse test used to minimize self-heating effect.

8. Guaranteed by design. Not subject to product testing.

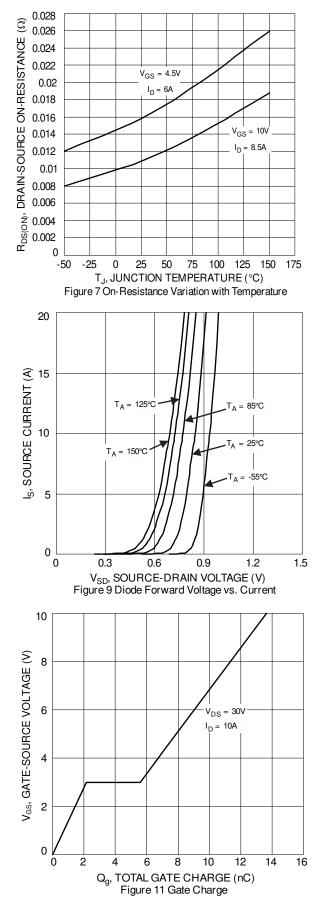


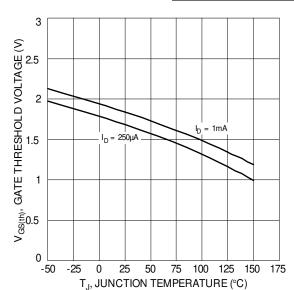
DMT616MLSS



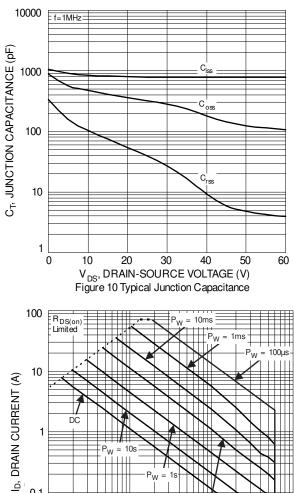












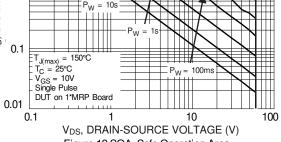
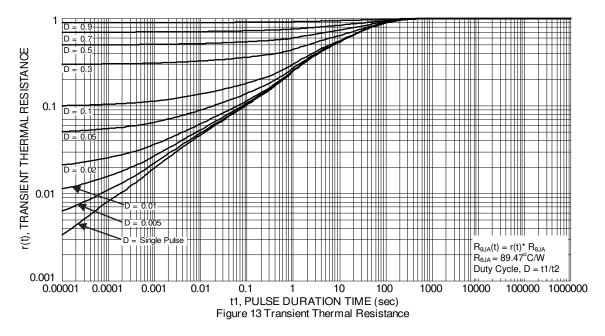


Figure 12 SOA, Safe Operation Area

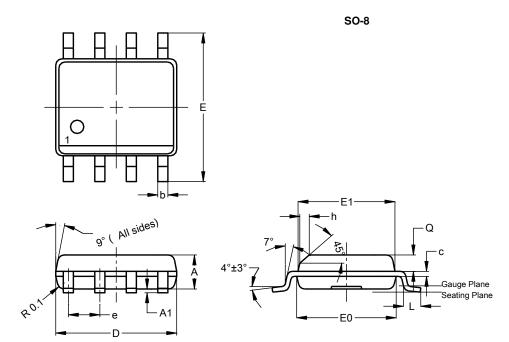






Package Outline Dimensions

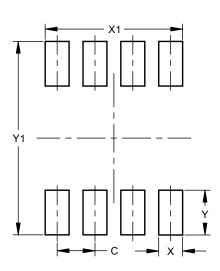
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SO-8 | | | | | |
|----------------------|------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.40 | 1.50 | 1.45 | | |
| A1 | 0.10 | 0.20 | 0.15 | | |
| b | 0.30 | 0.50 | 0.40 | | |
| С | 0.15 | 0.25 | 0.20 | | |
| D | 4.85 | 4.95 | 4.90 | | |
| Е | 5.90 | 6.10 | 6.00 | | |
| E1 | 3.80 | 3.90 | 3.85 | | |
| E0 | 3.85 | 3.95 | 3.90 | | |
| е | | | 1.27 | | |
| h | _ | _ | 0.35 | | |
| L | 0.62 | 0.82 | 0.72 | | |
| Q | 0.60 | 0.70 | 0.65 | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SO-8

| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 1.27 | | | |
| Х | 0.802 | | | |
| X1 | 4.612 | | | |
| Y | 1.505 | | | |
| Y1 | 6.50 | | | |



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